 ROBL-CRG	Experiment title: Nanophase formation in ZnO implanted with transition or rare earth metal ions	Experiment number: 20-02-634
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Report:

Recently due to the potential application in spintronics, both magnetic/semiconductor hybrid heterostructure and diluted magnetic semiconductor (DMS) have attracted huge research attention [1]. In both research fields, GaAs is the most intensively studied material. Epitaxial MnAs and transition metal (e.g. Fe) were achieved on GaAs substrates due to their structure compatibility: i.e. Mn-based metallic compounds have common III/column atoms with GaAs, while Fe/GaAs has a cube-on-cube orientation with a small lattice mismatch of -1.4% [2, 3]. Room temperature spin injection was reported from MnAs [4] and Fe [5] into GaAs. In parallel, Mn doped GaAs has been demonstrated to be a DMS with a Curie temperature of 110 K [6]. Very recently, wide-band-gap semiconductors (GaN and ZnO) doped with transition metals were reported to be DMS with Curie temperatures above room temperature [7]. Nevertheless, the origin of the observed ferromagnetism is still controversial, e.g. ferromagnetic clusters [8]. In contrast, only a few investigations deal with epitaxial magnetic/ZnO(or GaN) heterostructures. This is partially due to the chemical incompatibility, the different crystal symmetry or the large lattice mismatch between the 3d-ferromagnet and ZnO. For instance, Fe is a bcc crystal, while hcp MnAs and Co have a very large lattice mismatch with ZnO (12% and 23%, respectively). In this paper, we made an extensive investigation on the structural and magnetic properties evolution of Fe implanted ZnO upon annealing, and demonstrate the possibility to form epitaxial magnetic Zn-ferrite embedded in ZnO. With respect to the crystal symmetry and lattice mismatch, our results suggest that other ferrites, which have been epitaxially grown onto MgO, SrTiO₃, and Y_{0.15}Zr_{0.85}O₂, and exhibit rich magnetic properties [9], could be epitaxially embedded inside or grown onto ZnO.

From the experiment we have reached two conclusions:

- (1) By correlating the structural and magnetic properties of Fe-implanted ZnO, we found either bcc-Fe or partially inverted ZnFe₂O₄ nanocrystals are the origin of the observed ferromagnetism.
- (2) We demonstrate the possibility to form epitaxial magnetic Zn-ferrite embedded in ZnO, and the epitaxial relationship is ZnFe₂O₄ (111)[110]//ZnO(0001)[1120].

Fig. 1 shows the SR-XRD patterns for the as-implanted and annealed samples. For the as-implanted sample, Fe nanoparticles were observed, and no other Fe-oxide (Fe_2O_3 , Fe_3O_4 , and ZnFe_2O_4) particles were detected. After 823 K and 15 min annealing, larger and more Fe nanoparticles are formed. After 1073 K and 15 min annealing, the Fe(110) peak almost disappeared and the sample already shows an indication for the presence of ZnFe_2O_4 . After 3.5 hours annealing at 1073 K, crystalline and oriented ZnFe_2O_4 particles are clearly identified. The inset shows a zoom of the Fe(110) peak to show the development of Fe nanoparticles more clearly.

Fig. 2 shows the pole figure for $\text{ZnFe}_2\text{O}_4(511)$ and $\text{ZnFe}_2\text{O}_4(333)$. Both diffraction lines have the same Bragg angle in the cubic ZnFe_2O_4 . The sample tilt, χ , is the angle by which the surface is tilted out of the diffraction plane. The angle of rotation about the surface normal is denoted by ϕ , which ranges from -60° to 60° . The pole figure shows poles at $\chi \sim 39^\circ$, 56° and 70° , respectively, with sixfold symmetry and an indication of a tail from $\text{ZnO}(11\bar{2}0)$. It is consistent with the theoretic $\text{ZnFe}_2\text{O}_4(511) / (333)$ pole figure viewed along $[111]$ with rotation twins. The in-plane orientation relationship is $\text{ZnFe}_2\text{O}_4[110]//\text{ZnO}[11\bar{2}0]$.

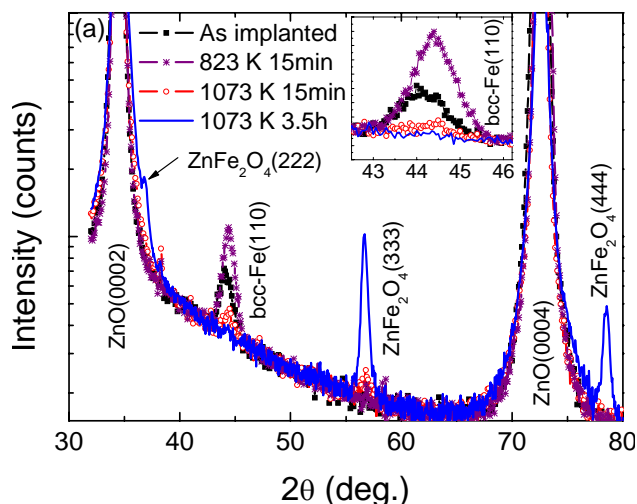


Fig. 1: SR-XRD patterns of Fe implanted ZnO reveal the second phase development (from bcc-Fe to ZnFe_2O_4) upon annealing.

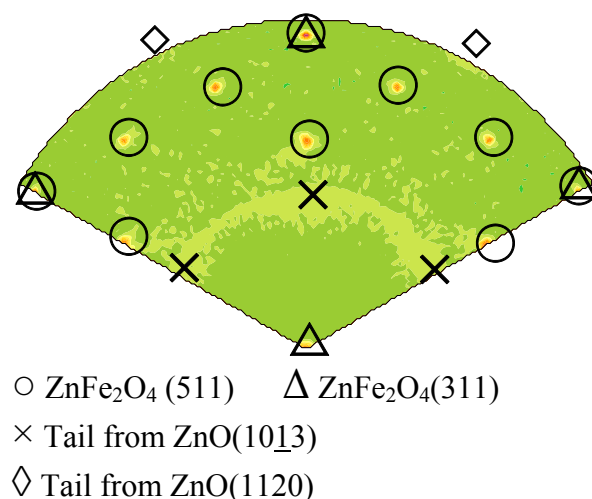


Fig. 2: Pole figure of $\text{ZnFe}_2\text{O}_4(511)$ reveals the epitaxy of ZnFe_2O_4 .

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